

74AHCT00

QUADRUPLE 2-INPUT NAND GATES

Description

The 74AHCT00 provides provides four independent 2-input NAND gates with standard push-pull outputs. The device is designed for operation with a power supply range of 4.5V to 5.5V.

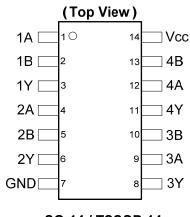
The gates perform the Boolean function:

 $Y = \overline{A \bullet B} \text{ or } Y = \overline{A} + \overline{B}$

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet



Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	V _{CC}	Supply Voltage

Function Table

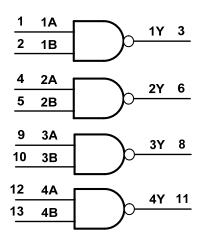
Ing	Output	
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
Input Clamp Current VI < -0.5V		-20	mA
I _{OK} Output Clamp Current V _O < 0V		-20	mA
I _{OK} Output Clamp Current V _O > V _{CC}		20	mA
lo	Continuous Output Current 0V < V _O < V _{CC}	+/- 25	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND} Continuous Current Through GND		-50	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ρτοτ	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Logic Diagram





Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	Vcc	V
Δt/ΔV	Input Transition Rise or Fall Rate		20	ns/V
T _A	Operating Free-Air Temperature	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symphol	Parameter	Test Conditions	v	T _A = -40°	C to +85°C	T _A = -40°C	to +125°C	Unit	
Symbol	Parameter	rest conditions	Vcc	Min	Max	Min	Max	Unit	
VIH	High-Level Input Voltage		4.5V to 5.5V	2.0		2.0		V	
VIL	Low-Level Input voltage		4.5V to 5.5V		0.8		0.8	V	
N/	High-Level	I _{OH} = -50μA	4.5V	4.4		4.4		V	
V _{OH}	Output Voltage	I _{OH} = -8mA	4.5V	3.80		3.70		7 V	
	Low-Level	I _{OL} = 50μA	4.5V		0.1		0.1	V	
Vol	Output Voltage	I _{OL} = 8mA	4.5V		0.44		0.55	- V	
l _l	Input Current	V _I =GND to 5.5V	3.6V		±1		±2	μA	
Icc	Supply Current	$V_{I} = GND \text{ or } V_{CC}, I_{O} = 0$	3.6V		20		40	μA	
ΔI_{CC}	Additional Supply Current	One input at V_{CC} -2.1V Other pins at V_{CC} or GND	5.5V		1.35		5	mA	

Operating Characteristics

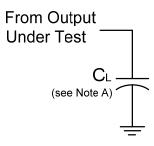
Parameter		Test Conditions	V _{CC} = 5.5V Typ	Unit
C _{pd}	Power dissipation capacitance per gate	f = 1MHz	14.8	pF
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	4.0	pF

Switching Characteristics

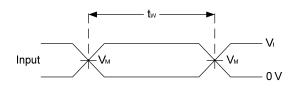
Symbol	Parameter	Test	V	٦	Γ _A = +25°C	;	-40°C to	o +85°C	-40°C to	+125°C	Unit
Symbol	Parameter	Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
	Propagation Delay	Figure 1 C _L = 15pF	4.5V to 5.5V	0.5	3.4	6.9	0.5	8.0	0.5	9.0	20
t _{PD}	A_N to Y_N	Figure 1 C _L = 50pF	4.5V to 5.5V	0.5	4.9	10.0	0.5	10.0	0.5	11.0	ns



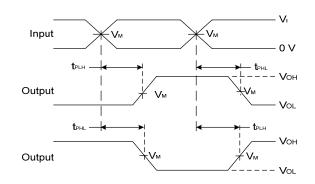
Parameter Measurement Information



N	Inputs		VM	VM	<u>^</u>
Vcc	VI	t _r /t _f	Inputs	Outputs	υL
4.5V to 5.5V	3.0 V	3ns	1.5 V	V _{CC} /2	15pF, 50pF



Voltage Waveform Pulse Duration



Voltage Waveform **Propagation Delay Times** Inverting and Non Inverting Outputs

Figure 1 Load Circuit and Voltage Waveforms

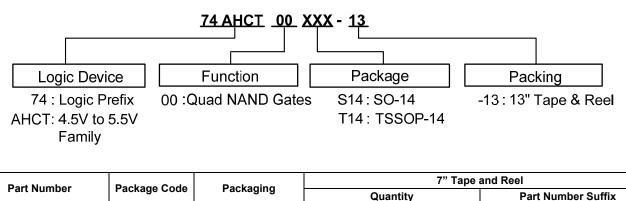
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 1 MHz. C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



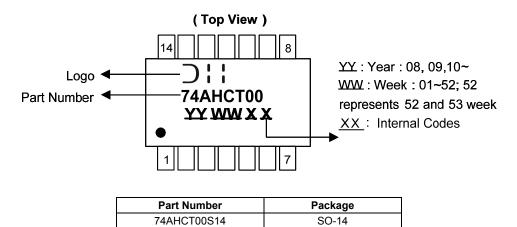
Ordering Information



	Part Number	Package Code	Packaging	7" Tape a	and Reel
	Fait Number	Fackage Coue	Packaging	Quantity	Part Number Suffix
Lead-free Green	74AHCT00S14-13	S14	SO-14	2500/Tape & Reel	-13
Lead-free Green	74AHCT00T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14



TSSOP-14

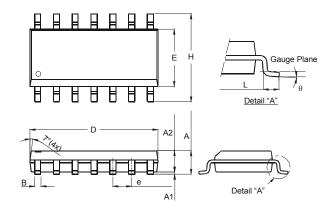
74AHCT00T14



Package Outline Dimensions (All dimensions in mm.)

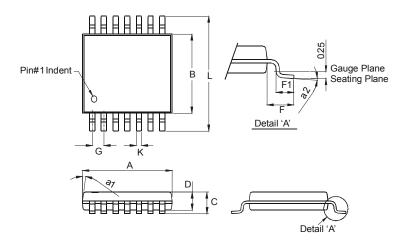
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14		
Dim	Min	Max	
Α	1.47	1.73	
A1	0.10	0.25	
A2	1.45 Typ		
в	0.33	0.51	
D	8.53	8.74	
Е	3.80	3.99	
е	1.27	Тур	
н	5.80	6.20	
L	0.38	1.27	
θ	0°	8°	
All Dir	nensions	in mm	

Package Type: TSSOP-14



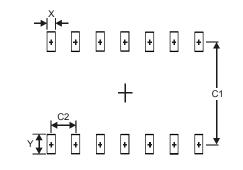
Т	SSOP-1	4		
Dim	Min	Max		
a1	7° (4	4X)		
a2	0°	8°		
Α	4.9	5.10		
В	4.30	4.50		
С		1.2		
D	0.8	1.05		
F	1.00	Тур		
F1	0.45	0.75		
G	0.65	Тур		
κ	0.19	0.30		
L 6.40 Typ				
All Dimensions in				
	mm			



Suggested Pad Layout

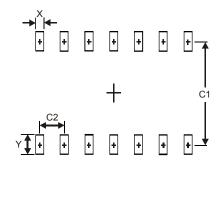
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimension	Value (in
S	mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimension	Value (in
s	mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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